



Identification

DTM60114:64Mx64 DTM60116:64Mx72 Performance range

133MHz (7.5ns@ CL=3)

Features

Burst mode operation

Auto & self refresh capability (4096 Cycles/64ms)

LVTTL compatible inputs and outputs

Single 3.3V±0.3V power supply

MRS cycle with address key programs Latency (Access from column adress) Burst length (1, 2, 4 & 8 page) Data scramble (Sequential & Interleave)

Serial presence detect with EEPROM

168-pin PC133 DIMM double-sided assembly 5.250" wide by 1.70" high

Description

The Dataram DTM60114 and DTM60116 are registered 64Mx64 and 64Mx72 Synchronous Dynamic RAM high density memory modules. The assemblies consist of sixteen stacked 64Mx4bit and eighteen stacked 64Mx4bit SDRAMS in two TSOP-II 400MII packages, respectively. Three 18bits Drive ICs for input control, one PLL for clock, and one 2K EEPROM for Serial Presence Detect are also installed on a 168-pin glass-epoxy substrate. Sychronous design allows for precise cycle control with the use of a system clock. The DTM60114 and DTM60116 are Dual in-line Memory Modules intended for mounting into 168-pin edge connector sockets.